## **Assignment 6 Solutions**

Electrical resistance between concentric cylinders

Since  $\mathbf{E} = -\nabla \varphi$ , we get

$$\mathbf{E} = -\frac{A}{r}\,\hat{\mathbf{r}}$$

for the given  $\varphi(r)$ . This is the electric field of a line charge, which has the same symmetry, and therefore satisfies  $\nabla \cdot \mathbf{E} = 0$  everywhere (except r = 0), which covers our case because there is no charge in the region between the two cylinders. Though the constant A is still to be determined, from this  $\mathbf{E}$  we can find the current density:

$$\mathbf{j} = (1/\rho) \mathbf{E} = -\left(\frac{A}{\rho}\right) \frac{1}{r} \hat{\mathbf{r}} .$$

Now consider a cylindrical surface S of radius r and length L matching the length of the two conductors. The flux of current density through S is the total current I flowing between the conductors:

$$I = \oint_{\mathcal{S}} \mathbf{j} \cdot d\mathbf{a}$$

Since there is no flux through the two ends of S, we only need the area element  $d\mathbf{a} = |d\mathbf{a}|\hat{\mathbf{r}}$  on the curved part of the surface,  $S_c$ , for the flux integral:

$$I = -\int_{\mathcal{S}_c} \left(\frac{A}{\rho}\right) \frac{1}{r} |d\mathbf{a}| = -\left(\frac{A}{\rho}\right) \frac{1}{r} \int_{\mathcal{S}_c} |d\mathbf{a}| = -\left(\frac{A}{\rho}\right) 2\pi L$$

The last step follows from the fact that  $S_c$  has area  $2\pi rL$ . The difference of potentials gives us the value of A,

$$V = \varphi(a) - \varphi(b) = A \log a - A \log b = A \log(a/b) = -A \log(b/a) ,$$

where A > 0 (V < 0) corresponds to the outer conductor being at the higher potential and positive current flowing inward (I < 0). Solving for A and substituting into the equation for I we obtain

$$I = \left(\frac{V}{\rho \log(b/a)}\right) 2\pi L \; ,$$

from which we get the resistance

$$R = V/I = \frac{\rho \log(b/a)}{2\pi L}$$

This is consistent with the general relationship  $R = \rho/\text{length}$ .

## A compound resistor

• Find the ratio of electric fields in the two semiconductors,  $E_1/E_2$ , when a potential difference is applied between the ends of the compound resistor. Since the same current (net charge per unit time) flows through both conductors,

$$I_1 = Aj_1 = I_2 = Aj_2$$
  
and  $j = E/\rho$  we get  
$$E_1/\rho_1 = E_2/\rho_2$$
  
or  
$$E_1/E_2 = \rho_1/\rho_2 .$$

• Find the ratio of potential differences between the ends of the individual semiconductors,  $V_1/V_2$ , when a potential difference is applied between the ends of the compound resistor.

Since V = EL,

$$\frac{V_1}{V_2} = \frac{E_1 L_1}{E_2 L_2} = \frac{\rho_1 L_1}{\rho_2 L_2} ,$$

where we substituted the electric field ratio from above.

• Find the current *I* that flows along the compound resistor when the potential difference between its ends is *V*.

The total potential change on the compound resistor is

$$V = V_1 + V_2 = E_1 L_1 + E_2 L_2 \; .$$

Using the electric field ratio from above we can express this in terms of only  $E_1$ :

$$V = E_1(L_1 + (\rho_2/\rho_1)L_2) .$$
(1)

Using conductor 1 to define the common current I,

$$I = Aj_1 = AE_1/\rho_1$$

we use equation (1) to express  $E_1$  in terms of V and substitute into this equation:

$$I = A\left(\frac{V}{L_1 + (\rho_2/\rho_1)L_2}\right)\frac{1}{\rho_1} \ .$$

We see that the resistance of the compound resistor,

$$R = V/I = \rho_1(L_1/A) + \rho_2(L_2/A)$$
,

is the "series" resistance.

• Explain why in general a surface charge density  $\sigma$  forms where the cylinders are joined and there is a nonzero potential V between the ends of the compound resistor. Calculate the value of  $\sigma$ .

Just from the fact that there is a different electric field on the two sides of the surface where the conductors make contact, there must be a surface charge density to account for the nonzero net flux of electric field at this surface. Using Gauss's law on a small cylindrical surface that straddles the surface, we obtain

$$E_2 - E_1 = \sigma/\epsilon_0$$
.

We can again express this in terms of just  $E_1$  using the electric field ratio:

$$((\rho_2/\rho_1) - 1)E_1 = \sigma/\epsilon_0$$

Substituting the  $E_1$  from equation (1) this becomes

$$((\rho_2/\rho_1) - 1)\left(\frac{V}{L_1 + (\rho_2/\rho_1)L_2}\right) = \sigma/\epsilon_0.$$

Finally, solving for  $\sigma$  we obtain

$$\sigma = \epsilon_0 \left( \frac{\rho_2 - \rho_1}{\rho_1 L_1 + \rho_2 L_2} \right) V$$

The surface charge density can be of either sign, depending on the sign of V (direction of the current) and which of the conductors has the greater resistivity.